NSN 5962-01-110-7712

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-110-7712 **Body Length:** Between 1.245 inches and 1.255 inches **Body Width:** Between 0.535 inches and 0.545 inches **Body Height:** 0.150 inches **Maximum Power Dissipation Rating:** 500.0 milliwatts **Operating Tempurature Range:** -0.0/+70.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and positive outputs and low power and 3-state output and high speed **Inclosure Material: Plastic Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 15 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 8.0 volts power source **Time Rating Per Chacteristic:** 500.00 nanoseconds propagation delay time, low to high level output and 500.00 nanoseconds propagation delay time, high to low level output **Memory Device Type: Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

Fiig:

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